

# NSN 5961-01-645-7367

Thyristor Semiconductor Device - Page 1 of 1



View Online at <https://aerobasegroup.com/nsn/5961-01-645-7367>

**Inclosure Material:**

Metal

**Overall Length:**

0.170 inches

**Mounting Method:**

Terminal

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

10.0 base to collector voltage, dc

**Current Rating Per Characteristic:**

10.0 milliamperes base current, dc

**Power Rating Per Characteristic:**

360.0 milliwatts average gate power dissipation

**Product Name:**

Semiconductor device

**Terminal Type And Quantity:**

3 uninsulated wire lead

**Shelf Life:**

N/a

**Unit Of Measure:**

--

**Demilitarization:**

No

**Fig:**

A110a0